



# Bipolar NPN Bare Die – BTN907

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## Part Description

The BTN907 is a silicon BJT transistor available in bare die form and well suited for use in High Voltage Driver applications.

## Key Parameters:

- VCBO = 400V
- VCEO = 400V
- VEBO = 5V
- hFE = 50 @ VCE = 5V, IC = 0.1A
- VCE(Sat) = 0.5V @ IC = 0.1A, IB = 10mA
- fT = 50 MHz @ VCE = 20V, IE = 0A
- COBO = 10pF @ VCB = 20V

## Features

Designed to provide performance equivalent to ZETEX / DIODES INC. FZT658

## Die Size (Unawn)

1130 $\mu$ m X 1130 $\mu$ m, 44 Mils X 44 Mils

This is a shortform datasheet only

For the full datasheet

Please contact [sales@siliconsupplies.com](mailto:sales@siliconsupplies.com)

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